

# SN74LV8T541 Octal Buffers and Drivers with 3-State Outputs and Logic-Level Shifter

### 1 Features

- Wide operating range of 1.65V to 5.5V
- 5.5V tolerant input pins
- Single-supply voltage translator (refer to LVxT Enhanced Input Voltage):
  - Up translation:
    - 1.2V to 1.8V
    - 1.5V to 2.5V
    - 1.8V to 3.3V
    - 3.3V to 5.0V
  - Down translation:
    - 5.0V, 3.3V, 2.5V to 1.8V
    - 5.0V, 3.3V to 2.5V
    - 5.0V to 3.3V
- Up to 150Mbps with 5V or 3.3V  $V_{CC}$
- Supports standard function pinout
- Latch-up performance exceeds 250mA per JESD 17

## 2 Applications

- Digital signage
- Controlling an indicator LED
- Increase the number of outputs on a microcontroller

## 3 Description

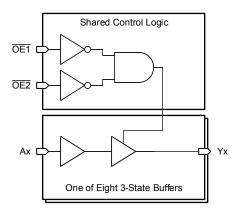
The SN74LV8T541 contains eight buffers with 3-state outputs. The active low output enable pins (OE1 and OE2) control all eight channels, and are configured so that both must be low for the outputs to be active.

The input is designed with a reduced threshold circuit to support up translation when the supply voltage is larger than the input voltage. Additionally, the 5V tolerant input pins enable down translation when the input voltage is larger than the supply voltage. The output level is always referenced to the supply voltage (V<sub>CC</sub>) and supports 1.8V, 2.5V, 3.3V, and 5V CMOS levels.

### **Package Information**

PART NUMBER	PACKAGE <sup>(1)</sup>	PACKAGE SIZE <sup>(2)</sup>	BODY SIZE (NOM) <sup>(3)</sup>
	PW (TSSOP, 20)	6.5mm × 6.4mm	6.5mm × 4.4mm
SN74LV8T541	DGS (SOT, 20)	5.1mm × 4.9mm	5.1mm × 3.0mm
	RKS (WQFN, 20)	4.5mm × 2.5mm	4.5mm × 2.5mm

- For more information, see Mechanical, Packaging, and Orderable Information.
- The package size (length × width) is a nominal value and includes pins, where applicable.
- The body size (length × width) is a nominal value and does not include pins.



Simplified Logic Diagram (Positive Logic)



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# **4 Pin Configuration and Functions**

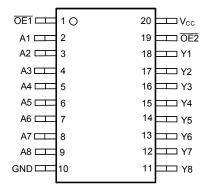


Figure 4-1. PW and DGS Package, 20-Pin TSSOP (Top View)

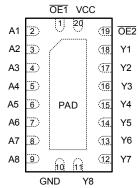


Figure 4-2. RKS Package, 20-Pin VQFN (Transparent Top View)

**Table 4-1. Pin Functions** 

	PIN	TYPE <sup>(1)</sup>	DECODINE		
NAME	NO.	IYPE	DESCRIPTION		
OE1	1	I	Output enable input 1, active low		
A1	2	I	Input for channel 1		
A2	3	I	Input for channel 2		
A3	4	I	Input for channel 3		
A4	5	I	Input for channel 4		
A5	6	I	Input for channel 5		
A6	7	I	Input for channel 6		
A7	8	I	Input for channel 7		
A8	9	I	Input for channel 8		
GND	10	G	Ground		
Y8	11	0	Output for channel 8		
Y7	12	0	Output for channel 7		
Y6	13	0	Output for channel 6		
Y5	14	0	Output for channel 5		
Y4	15	0	Output for channel 4		
Y3	16	0	Output for channel 3		
Y2	17	0	Output for channel 2		
Y1	18	0	Output for channel 1		
OE2	19	I	Output enable input 2, active low		
V <sub>CC</sub>	20	Р	Positive supply		

(1) I = Input, O = Output, I/O = Input or Output, G = Ground, P = Power



## **5 Specifications**

## 5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range	Supply voltage range			
VI	Input voltage range <sup>(2)</sup>		-0.5	7	V
Vo	Voltage range applied to any outp	ut in the high-impedance or power-off state <sup>(2)</sup>	-0.5	7	V
Vo	Output voltage range <sup>(2)</sup>		-0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> < -0.5V		-20	mA
I <sub>OK</sub>	Output clamp current	$V_{O}$ < -0.5V or $V_{O}$ > $V_{CC+}$ 0.5V		±20	mA
Io	Continuous output current	$V_O = 0$ to $V_{CC}$		±25	mA
	Continuous output current through		±75	mA	
T <sub>stg</sub>	Storage temperature		-65	150	°C

<sup>(1)</sup> Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute maximum ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If briefly operating outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not sustain damage, but it may not be fully functional. Operating the device in this manner may affect device reliability, functionality, performance, and shorten the device lifetime.

(2) The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

## 5.2 ESD Ratings

			VALUE	UNIT
V	Electrostatic	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	±2000	\/
V <sub>(ESD)</sub>	discharge	Charged-device model (CDM), per ANSI/ESDA/JEDEC JS-002 <sup>(2)</sup>	±1000	٧

<sup>(1)</sup> JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.

## **5.3 Recommended Operating Conditions**

over operating free-air temperature range (unless otherwise noted)

Specifications	Description	Condition	MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		1.65	5.5	V
VI	Input voltage		0	5.5	V
Vo	Output voltage		0	V <sub>CC</sub>	V
		V <sub>CC</sub> = 1.65V to 2V	1.1		
V	High lovel input veltage	V <sub>CC</sub> = 2.25V to 2.75V	1.28		V
V <sub>IH</sub>	High-level input voltage	V <sub>CC</sub> = 3V to 3.6V	1.45		V
		V <sub>CC</sub> = 4.5V to 5.5V	2		
		V <sub>CC</sub> = 1.65V to 2V		0.51	
		V <sub>CC</sub> = 2.25V to 2.75V		0.65	V
V <sub>IL</sub>	Low-Level input voltage	V <sub>CC</sub> = 3V to 3.6V		0.75	
		V <sub>CC</sub> = 4.5V to 5.5V		0.8	
		V <sub>CC</sub> = 1.6V to 2V		±8	
Io	Output current	V <sub>CC</sub> = 2.25V to 2.75V		±15	mA
		V <sub>CC</sub> = 3.3V to 5.0V		±25	
Δt/Δν	Input transition rise or fall rate	V <sub>CC</sub> = 1.6V to 5.0V		20	ns/V
T <sub>A</sub>	Operating free-air temperature	Operating free-air temperature			°C

Product Folder Links: SN74LV8T541

<sup>(2)</sup> JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.



## **5.4 Thermal Information**

PACKAGE	PINS	THERMAL METRIC(1)						
PACKAGE	FINS	R <sub>0JA</sub>	R <sub>0JC(top)</sub>	R <sub>0JB</sub>	$\Psi_{JT}$	$\Psi_{JB}$	R <sub>0JC(bot)</sub>	UNIT
DGS (VSSOP)	20	131.6	69.5	86.7	10.9	85.9	N/A	°C/W
PW (TSSOP)	20	116.8	58.5	78.7	12.6	77.9	N/A	°C/W
RKS (VQFN)	20	90.4	92.2	63.4	29	63.5	41.3	°C/W

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application note.

## 5.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMET	TEGT COMPLETIONS	N/	T <sub>A</sub> =	25°C		-40°C to 125°C			
ER	TEST CONDITIONS	V <sub>cc</sub>	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
	I <sub>OH</sub> = -50μA	1.65V to 5.5V	V <sub>CC</sub> -0.1			V <sub>CC</sub> -0.1			
	I <sub>OH</sub> = -2mA	1.65V to 2V	1.28	1.7 <sup>(1)</sup>		1.21			
V <sub>OH</sub>	I <sub>OH</sub> = -3mA	2.25V to 2.75V	2	2.4 <sup>(1)</sup>		1.93			V
	I <sub>OH</sub> = -5.5mA	3V to 3.6V	2.6	3.08(1)		2.49			
	I <sub>OH</sub> = -8mA	4.5V to 5.5V	4.1	4.65 <sup>(1)</sup>		3.95			
	I <sub>OL</sub> = 50μA	1.65V to 5.5V			0.1			0.1	
	I <sub>OL</sub> = 2mA	1.65V to 2V		0.1 <sup>(1)</sup>	0.2			0.25	
V <sub>OL</sub>	I <sub>OL</sub> = 3mA	2.25V to 2.75V		0.15 <sup>(1)</sup>	0.17			0.2	V
	I <sub>OL</sub> = 5.5mA	3V to 3.6V		0.2(1)	0.23			0.25	
	I <sub>OL</sub> = 8mA	4.5V to 5.5V		0.3(1)	0.3			0.35	
I <sub>I</sub>	V <sub>I</sub> = 0V or V <sub>CC</sub>	0V to 5.5V			±0.1			±1	μA
I <sub>CC</sub>	$V_I = 0V$ or $V_{CC}$ , $I_O = 0$ ; open on loading	1.65V to 5.5V			2			20	μΑ
A1	One input at 0.3V or 3.4V, other inputs at 0 or $V_{CC}$ , $I_{O} = 0$	5.5V			1.35			1.5	mA
ΔI <sub>CC</sub>	One input at 0.3V or 1.1V, other inputs at 0 or $V_{CC}$ , $I_{O} = 0$	1.8V			10			20	μA
I <sub>OZ</sub>	$V_O = V_{CC}$ or GND and $V_{CC} = 5.5V$	5.5V			±0.25			±2.5	μΑ
Cı	V <sub>I</sub> = V <sub>CC</sub> or GND	5V		4	10			10	pF
Co	V <sub>O</sub> = V <sub>CC</sub> or GND	5V		5					pF
C <sub>PD</sub>	No load, F = 1MHz	5V		17					pF

<sup>(1)</sup> Typical value at nearest nominal voltage (1.8V, 2.5V, 3.3V, and 5V)



## **5.6 Switching Characteristics**

Over operating free-air temperature range; typical values measured at  $T_A$  = 25°C (unless otherwise noted). See *Parameter Measurement Information*.

PARAM	EDOM (INDUE)	TO (OUTDUE)	LOAD	V	T	= 25°C	-40°	LIMIT		
ETER	FROM (INPUT)	TO (OUTPUT)	CAPACITANCE	V <sub>cc</sub>	MIN	TYP MA	X MIN	TYP MAX	UNIT	
t <sub>PLH</sub>	^	Υ	C <sub>L</sub> = 15pF	1.9\/	5.3	12	1 4.8	13.4	ns	
t <sub>PHL</sub>	A	Ť	C <sub>L</sub> = 15pr	1.8V	6.7	15	8 5.9	17.4	ns	
t <sub>PZH</sub>	ŌĒ	Υ	C = 15pF	1.0)/	9	20	5 7.9	23	ns	
t <sub>PZL</sub>	JOE	Ť	C <sub>L</sub> = 15pF	1.8V	8.1	19	3 7.1	21.4	ns	
t <sub>PHZ</sub>	ŌĒ	Υ	C = 15pF	1.0)/	7	13	2 6.3	15	ns	
t <sub>PLZ</sub>	JOE	Ť	C <sub>L</sub> = 15pF	1.8V	6.7	11	7 6.3	12.9	ns	
t <sub>PLH</sub>	^	Υ	C = 50pF	1.0)/	7.3	16	4 6.5	18.2	ns	
t <sub>PHL</sub>	A	Ť	C <sub>L</sub> = 50pF	1.8V	8.4	19	6 7.5	21.7	ns	
t <sub>PZH</sub>	ŌĒ	Υ	C = 50pF	1.0)/	11.4	25	1 9.9	28.2	ns	
t <sub>PZL</sub>	JOE	Ť	C <sub>L</sub> = 50pF	1.8V	10.1	23	5 9	26	ns	
t <sub>PHZ</sub>	ŌĒ	Υ	C = 50pF	1.0)/	12.8	20	5 12	22.5	ns	
t <sub>PLZ</sub>	JOE	Ť	C <sub>L</sub> = 50pF	1.8V	12.6	1	9 12	20.3	ns	
t <sub>sk(o)</sub>			C <sub>L</sub> = 50pF	1.8V		0	3	0.3	ns	
t <sub>PLH</sub>	^		0 - 45-5	2.51/	3.9	7	7 3.4	8.7	ns	
t <sub>PHL</sub>	A	Υ	$C_L = 15pF$	2.5V	4.9	9	8 4.3	11.2	ns	
t <sub>PZH</sub>	ŌĒ	Y	0 - 45-5	2.5V	6.6	12	6 5.7	14.7	ns	
t <sub>PZL</sub>	OE .		C <sub>L</sub> = 15pF	2.50	5.8	11	6 5	13.5	ns	
t <sub>PHZ</sub>	OF.		C <sub>L</sub> = 15pF	2.5V	5	8	5 4.4	9.8	ns	
t <sub>PLZ</sub>	ŌĒ	Υ			5.1	7	9 4.6	8.8	ns	
t <sub>PLH</sub>	^	.,	Υ	C - 50=5	2.5V	5.3	10	6 4.7	12	ns
t <sub>PHL</sub>	A	Y	C <sub>L</sub> = 50pF	2.5V	6.2	12	5 5.5	14.2	ns	
t <sub>PZH</sub>	<u></u>	.,		0.5)/	8.4	15	9 7.3	18.3	ns	
t <sub>PZL</sub>	ŌĒ	Υ	C <sub>L</sub> = 50pF	2.5V	7.5	14	7 6.7	16.9	ns	
t <sub>PHZ</sub>	OF.		0 50.5	0.5)/	8.8	13	4 8.1	14.8	ns	
t <sub>PLZ</sub>	ŌĒ	Υ	C <sub>L</sub> = 50pF	2.5V	9	12	8 8.5	13.8	ns	
t <sub>sk(o)</sub>			C <sub>L</sub> = 50pF	2.5V		0	3	0.3	ns	
t <sub>PLH</sub>		.,	0 45:5	0.014	3.4	6	3 3	7.3	ns	
t <sub>PHL</sub>	A	Υ	C <sub>L</sub> = 15pF	3.3V	4.2	8	1 3.7	9.3	ns	
t <sub>PZH</sub>	OF.		0 45:5	0.01/	5.7	10	3 5	11.9	ns	
t <sub>PZL</sub>	ŌĒ	Υ	C <sub>L</sub> = 15pF	3.3V	5	9	5 4.4	11	ns	
t <sub>PHZ</sub>	ŌĒ	Υ	0 - 45-5	2.2)/	3.7	6	7 3.2	7.9	ns	
t <sub>PLZ</sub>	OE .	Y	C <sub>L</sub> = 15pF	3.3V	4.4	6	6 4.1	7.4	ns	
t <sub>PLH</sub>	_	V	0 - 50:5	2.21/	4.6	8	8 4	10	ns	
t <sub>PHL</sub>	A	Υ	C <sub>L</sub> = 50pF	3.3V	5.5	10	4 4.9	11.9	ns	
t <sub>PZH</sub>	OF.		0 - 50::5	2.21/	7.4	13	1 6.4	15.1	ns	
t <sub>PZL</sub>	ŌĒ	Υ	C <sub>L</sub> = 50pF	3.3V	6.7	12	1 6	14	ns	
t <sub>PHZ</sub>	OF.		0 50 5	0.01/	7	10	5 6.5	11.7	ns	
t <sub>PLZ</sub>	ŌĒ	Υ	C <sub>L</sub> = 50pF	3.3V	7.6	10	6 7.3	11.4	ns	
t <sub>sk(o)</sub>			C <sub>L</sub> = 50pF	3.3V		0	2	0.2		
t <sub>PLH</sub>				_,,	3.1	5	4 2.9	6.1	ns	
t <sub>PHL</sub>	A	Y	C <sub>L</sub> = 15pF	5V	3.1	5		6.3	ns	



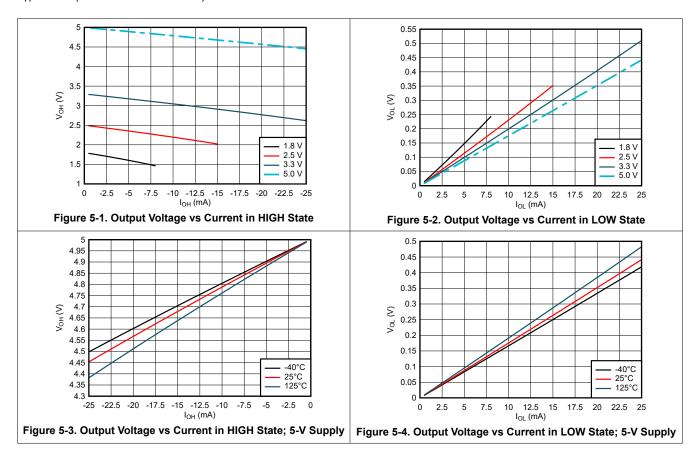
## **5.6 Switching Characteristics (continued)**

Over operating free-air temperature range; typical values measured at  $T_A$  = 25°C (unless otherwise noted). See *Parameter Measurement Information*.

PARAM	FROM (INPUT)	TO (OUTPUT)	LOAD	LOAD		= 25°C	-40°	C to 125°C	UNIT			
ETER	FROM (INFOT)	10 (001701)	CAPACITANCE	V <sub>cc</sub>	MIN	TYP MA	MIN	TYP MAX				
t <sub>PZH</sub>	ŌĒ	Υ	C <sub>1</sub> = 15pF	5V	4.3	7.	3.7	8.4	ns			
t <sub>PZL</sub>	OL	I	О[ – ТЭРГ	30	3.6	6.	3.2	7.6	ns			
t <sub>PHZ</sub>	ŌĒ	Υ	C <sub>1</sub> = 15pF	5V	3.1		2.7	5.8	ns			
t <sub>PLZ</sub>	OL	'	CL = 15pr	OL - 1391	OL - 1991	OL 10P1 0	St 1951	4.3		6 4	6.5	ns
t <sub>PLH</sub>	Α	V C = 50°F	Y C <sub>1</sub> = 50pF	5V	4.1	7.	3.7	8.1	ns			
t <sub>PHL</sub>		'	CL - 20bL	OL – Johi	30	4.2	7.	3.8	8.4	ns		
t <sub>PZH</sub>	<u>OE</u>	Y C <sub>1</sub> = 50pF 5V	5V	5.6	9.	4.9	10.9	ns				
t <sub>PZL</sub>	OL	'	О[ – 30рі	30	5	8.	4.5	9.9	ns			
t <sub>PHZ</sub>	- OE Y	0 - 50-5	5V	4.9	7.	4.6	8.1	ns				
t <sub>PLZ</sub>	OL	1	C <sub>L</sub> = 50pF	50	6.3	8.	6.1	8.9	ns			
t <sub>sk(o)</sub>			C <sub>L</sub> = 50pF	5V		0.	3	0.3	ns			

## 5.7 Typical Characteristics

T<sub>A</sub> = 25°C (unless otherwise noted)



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## 5.7 Typical Characteristics (continued)

T<sub>A</sub> = 25°C (unless otherwise noted)

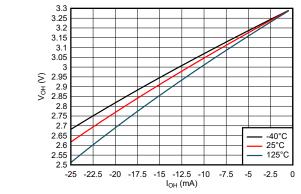


Figure 5-5. Output Voltage vs Current in HIGH State; 3.3-V Supply

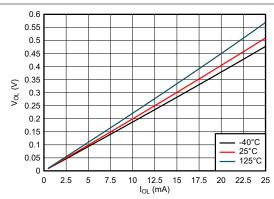


Figure 5-6. Output Voltage vs Current in LOW State; 3.3-V Supply

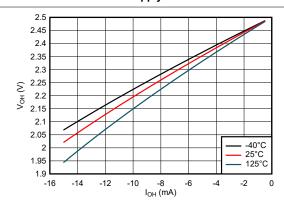


Figure 5-7. Output Voltage vs Current in HIGH State; 2.5-V Supply

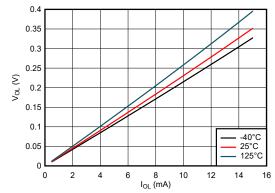


Figure 5-8. Output Voltage vs Current in LOW State; 2.5-V Supply

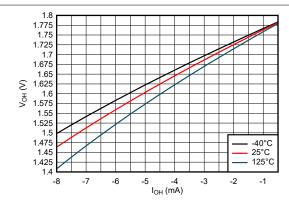


Figure 5-9. Output Voltage vs Current in HIGH State; 1.8-V Supply

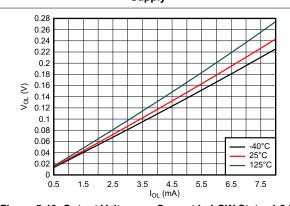


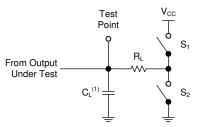
Figure 5-10. Output Voltage vs Current in LOW State; 1.8-V Supply

### **6 Parameter Measurement Information**

Phase relationships between waveforms were chosen arbitrarily for the examples listed in the following table. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1MHz,  $Z_O = 50\Omega$ ,  $t_t < 2.5$ ns.

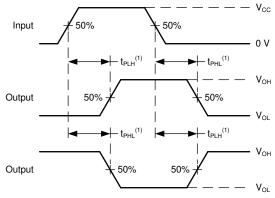
The outputs are measured individually with one input transition per measurement.

TEST	S1	S2	R <sub>L</sub>	CL	ΔV	V <sub>cc</sub>
t <sub>PLH</sub> , t <sub>PHL</sub>	OPEN	OPEN	_	15pF, 50pF	_	ALL
t <sub>PLZ</sub> , t <sub>PZL</sub>	CLOSED	OPEN	1kΩ	15pF, 50pF	0.15V	≤ 2.5V
t <sub>PHZ</sub> , t <sub>PZH</sub>	OPEN	CLOSED	1kΩ	15pF, 50pF	0.15V	≤ 2.5V
t <sub>PLZ</sub> , t <sub>PZL</sub>	CLOSED	OPEN	1kΩ	15pF, 50pF	0.3V	> 2.5V
t <sub>PHZ</sub> , t <sub>PZH</sub>	OPEN	CLOSED	1kΩ	15pF, 50pF	0.3V	> 2.5V



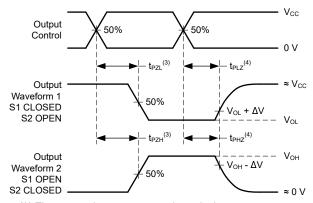
(1) C<sub>L</sub> includes probe and test-fixture capacitance.

Figure 6-1. Load Circuit for 3-State Outputs



(1) The greater between  $t_{\text{PLH}}$  and  $t_{\text{PHL}}$  is the same as  $t_{\text{pd}}$ .

Figure 6-2. Voltage Waveforms Propagation Delays



- (3) The greater between  $t_{PZL}$  and  $t_{PZH}$  is the same as  $t_{en}$ .
- (4) The greater between  $t_{\text{PLZ}}$  and  $t_{\text{PHZ}}$  is the same as  $t_{\text{dis}}$ .

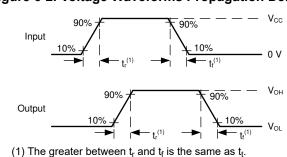


Figure 6-4. Voltage Waveforms, Input and Output Transition Times

Figure 6-3. Voltage Waveforms Propagation Delays



Noise values measured with all other outputs simultaneously switching.

Figure 6-5. Voltage Waveforms, Noise



## 7 Detailed Description

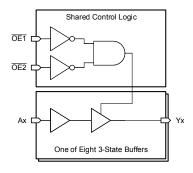
### 7.1 Overview

The SN74LV8T541 contains eight buffers with 3-state outputs. The active low output enable pins ( $\overline{OE1}$  and  $\overline{OE2}$ ) control all eight channels, and are configured so that both must be low for the outputs to be active.

When the outputs are enabled, the outputs are actively driven low or high.

When the outputs are disabled, the outputs are set into the high-impedance state.

### 7.2 Functional Block Diagram



## **8 Feature Description**

### 8.1 Balanced CMOS 3-State Outputs

This device includes balanced CMOS 3-state outputs. Driving high, driving low, and high impedance are the three states that these outputs can be in. The term *balanced* indicates that the device can sink and source similar currents. The drive capability of this device may create fast edges into light loads, so routing and load conditions should be considered to prevent ringing. Additionally, the outputs of this device can drive larger currents than the device can sustain without being damaged. It is important for the output power of the device to be limited to avoid damage due to overcurrent. The electrical and thermal limits defined in the *Absolute Maximum Ratings* must be followed at all times.

When placed into the high-impedance state, the output will neither source nor sink current, with the exception of minor leakage current as defined in the *Electrical Characteristics* table. In the high-impedance state, the output voltage is not controlled by the device and is dependent on external factors. If no other drivers are connected to the node, then this is known as a floating node and the voltage is unknown. A pull-up or pull-down resistor can be connected to the output to provide a known voltage at the output while it is in the high-impedance state. The value of the resistor will depend on multiple factors, including parasitic capacitance and power consumption limitations. Typically, a  $10k\Omega$  resistor can be used to meet these requirements.

Unused 3-state CMOS outputs should be left disconnected.

### 8.2 LVxT Enhanced Input Voltage

The SN74LV8T541 belongs to Tl's LVxT family of logic devices with integrated voltage level translation. This family of devices was designed with reduced input voltage thresholds to support up-translation, and inputs tolerant of signals with up to 5.5V levels to support down-translation. For proper functionality, input signals must remain at or above the specified  $V_{IH(MIN)}$  level for a HIGH input state, and at or below the specified  $V_{IL(MAX)}$  for a LOW input state. Figure 8-1 shows the typical  $V_{IH}$  and  $V_{IL}$  levels for the LVxT family of devices, as well as the voltage levels for standard CMOS devices for comparison.

The inputs are high impedance and are typically modeled as a resistor in parallel with the input capacitance given in the *Electrical Characteristics*. The worst case resistance is calculated with the maximum input voltage, given in the *Absolute Maximum Ratings*, and the maximum input leakage current, given in the *Electrical Characteristics*, using Ohm's law (R = V ÷ I).

Input signals must transition between valid logic states quickly, as defined by the input transition rate in the *Recommended Operating Conditions* table. Failing to meet this specification will result in excessive power consumption and could cause oscillations. More details can be found in the *Implications of Slow or Floating CMOS Inputs* application report.

Do not leave inputs floating at any time during operation. Unused inputs must be terminated at a valid high or low voltage level. If a system will not be actively driving an input at all times, then a pull-up or pull-down resistor can be added to provide a valid input voltage during these times. The resistor value will depend on multiple factors; however, a  $10k\Omega$  resistor is recommended and will typically meet all requirements.

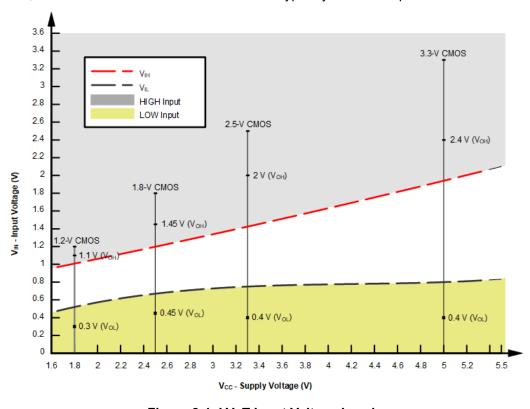


Figure 8-1. LVxT Input Voltage Levels



## 8.3 Clamp Diode Structure

As Figure 8-2 shows, the outputs to this device have both positive and negative clamping diodes, and the inputs to this device have negative clamping diodes only.

### **CAUTION**

Voltages beyond the values specified in the Absolute Maximum Ratings table can cause damage to the device. The input and output voltage ratings may be exceeded if the input and output clampcurrent ratings are observed.

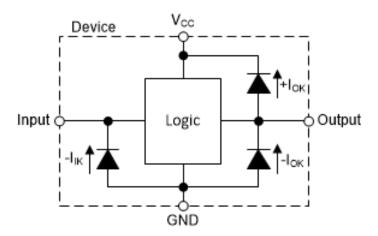


Figure 8-2. Electrical Placement of Clamping Diodes for Each Input and Output

## 9 Device Functional Modes

Table 9-1 lists the functional modes of the SN74LV8T541.

**Table 9-1. Function Table** 

	OUTPUT <sup>(2)</sup>		
OE1	ŌE2	Α	Y
L	L	L	L
L	L	Н	Н
Н	Х	Х	Z
Х	Н	Х	Z

Product Folder Links: SN74LV8T541

- (1) L = input low, H = input high, X = don't care
- L = output low, H = output high, Z = high impedance

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## 10 Application and Implementation

#### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

### 10.1 Application Information

The SN74LV8T541 can be used to drive signals over relatively long traces or transmission lines. A series damping resistor placed in series with the transmitter's output can be used to reduce ringing caused by impedance mismatches between the driver, transmission line, and receiver. The figure in the *Application Curve* section shows the received signal with three separate resistor values. Just a small amount of resistance can make a significant impact on signal integrity in this type of application.

## 10.2 Typical Application

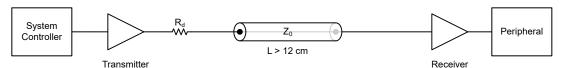


Figure 10-1. Typical Application Block Diagram

### 10.2.1 Design Requirements

#### 10.2.1.1 Power Considerations

Ensure the desired supply voltage is within the range specified in the *Recommended Operating Conditions*. The supply voltage sets the device's electrical characteristics as described in the *Electrical Characteristics*.

The positive voltage supply must be capable of sourcing current equal to the total current to be sourced by all outputs of the SN74LV8T541 plus the maximum static supply current, I<sub>CC</sub>, listed in the *Electrical Characteristics* and any transient current required for switching. The logic device can only source as much current as is provided by the positive supply source. Ensure the maximum total current through V<sub>CC</sub> listed in the *Absolute Maximum Ratings* is not exceeded.

The ground must be capable of sinking current equal to the total current to be sunk by all outputs of the SN74LV8T541 plus the maximum supply current, I<sub>CC</sub>, listed in the *Electrical Characteristics*, and any transient current required for switching. The logic device can only sink as much current as can be sunk into its ground connection. Ensure the maximum total current through GND listed in the *Absolute Maximum Ratings* is not exceeded.

The SN74LV8T541 can drive a load with a total capacitance less than or equal to 50pF while still meeting all of the data sheet specifications. Larger capacitive loads can be applied; however, it is not recommended to exceed 50pF.

The SN74LV8T541 can drive a load with total resistance described by  $R_L \ge V_O / I_O$ , with the output voltage and current defined in the *Electrical Characteristics* table with  $V_{OH}$  and  $V_{OL}$ . When outputting in the high state, the output voltage in the equation is defined as the difference between the measured output voltage and the supply voltage at the  $V_{CC}$  pin.

Total power consumption can be calculated using the information provided in *CMOS Power Consumption and Cpd Calculation*.

Thermal increase can be calculated using the information provided in *Thermal Characteristics of Standard Linear* and Logic (SLL) Packages and Devices.



#### **CAUTION**

The maximum junction temperature,  $T_{J(max)}$  listed in the *Absolute Maximum Ratings*, is an additional limitation to prevent damage to the device. Do not violate any values listed in the *Absolute Maximum Ratings*. These limits are provided to prevent damage to the device.

### 10.2.1.2 Input Considerations

Input signals must cross  $V_{IL(max)}$  to be considered a logic LOW, and  $V_{IH(min)}$  to be considered a logic HIGH. Do not exceed the maximum input voltage range found in the *Absolute Maximum Ratings*.

Unused inputs must be terminated to either  $V_{CC}$  or ground. These can be directly terminated if the input is completely unused, or they can be connected with a pull-up or pull-down resistor if the input is to be used sometimes, but not always. A pull-up resistor is used for a default state of HIGH, and a pull-down resistor is used for a default state of LOW. The resistor size is limited by drive current of the controller, leakage current into the SN74LV8T541, as specified in the *Electrical Characteristics*, and the desired input transition rate. A  $10k\Omega$  resistor value is often used due to these factors.

The SN74LV8T541 has CMOS inputs and thus requires fast input transitions to operate correctly, as defined in the *Recommended Operating Conditions* table. Slow input transitions can cause oscillations, additional power consumption, and reduction in device reliability.

Refer to the *Feature Description* section for additional information regarding the inputs for this device.

#### 10.2.1.3 Output Considerations

The positive supply voltage is used to produce the output HIGH voltage. Drawing current from the output will decrease the output voltage as specified by the  $V_{OH}$  specification in the *Electrical Characteristics*. The ground voltage is used to produce the output LOW voltage. Sinking current into the output will increase the output voltage as specified by the  $V_{OI}$  specification in the *Electrical Characteristics*.

Push-pull outputs that could be in opposite states, even for a very short time period, should never be connected directly together. This can cause excessive current and damage to the device.

Two channels within the same device with the same input signals can be connected in parallel for additional output drive strength.

Unused outputs can be left floating. Do not connect outputs directly to V<sub>CC</sub> or ground.

Refer to Feature Description section for additional information regarding the outputs for this device.

### 10.2.2 Detailed Design Procedure

- Add a decoupling capacitor from V<sub>CC</sub> to GND. The capacitor needs to be placed physically close to the device and electrically close to both the V<sub>CC</sub> and GND pins. An example layout is shown in the *Layout* section.
- 2. Ensure the capacitive load at the output is ≤ 50pF. This is not a hard limit; by design, however, it will optimize performance. This can be accomplished by providing short, appropriately sized traces from the SN74LV8T541 to one or more of the receiving devices.
- 3. Ensure the resistive load at the output is larger than  $(V_{CC} / I_{O(max)})\Omega$ . Doing this will prevent the maximum output current from the *Absolute Maximum Ratings* from being violated. Most CMOS inputs have a resistive load measured in M $\Omega$ ; much larger than the minimum calculated previously.
- 4. Thermal issues are rarely a concern for logic gates; the power consumption and thermal increase, however, can be calculated using the steps provided in the application report, CMOS Power Consumption and Cpd Calculation.

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### 10.2.3 Application Curves

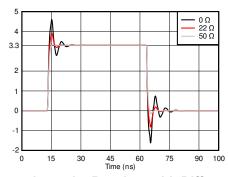


Figure 10-2. Simulated Signal Integrity at the Receiver with Different Damping Resistor (R<sub>d</sub>) Values

## 10.3 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each  $V_{CC}$  terminal should have a good bypass capacitor to prevent power disturbance. A  $0.1\mu F$  capacitor is recommended for this device. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise. The  $0.1\mu F$  and  $1\mu F$  capacitors are commonly used in parallel. As shown in the following layout example, install the bypass capacitor as close to the power terminal as possible for best results.

## 10.4 Layout

### 10.4.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices inputs must never be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or V<sub>CC</sub>, whichever makes more sense for the logic function or is more convenient.

#### 10.4.2 Layout Example

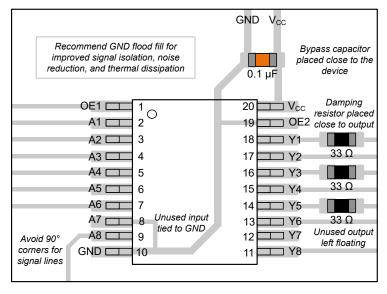


Figure 10-3. Example Layout for the SN74LV8T541 in TSSOP



## 11 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

## 11.1 Documentation Support

#### 11.1.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, CMOS Power Consumption and Cpd Calculation application report
- Texas Instruments, *Designing With Logic* application report
- Texas Instruments, Thermal Characteristics of Standard Linear and Logic (SLL) Packages and Devices application report

## 11.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 11.3 Support Resources

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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#### 11.4 Trademarks

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### 11.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### 11.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

## 12 Revision History

DATE	REVISION	NOTES
August 2025	*	Initial Release

# 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Product Folder Links: SN74LV8T541

www.ti.com

6-Nov-2025

### PACKAGING INFORMATION

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	<b>RoHS</b> (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
SN74LV8T541DGSR	Active	Production	VSSOP (DGS)   20	5000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	8T541
SN74LV8T541PWR	Active	Production	TSSOP (PW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV8T541
SN74LV8T541RKSR	Active	Production	VQFN (RKS)   20	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV8T541

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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#### OTHER QUALIFIED VERSIONS OF SN74LV8T541:

Automotive: SN74LV8T541-Q1

<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

## PACKAGE OPTION ADDENDUM

www.ti.com 6-Nov-2025

● Enhanced Product : SN74LV8T541-EP

NOTE: Qualified Version Definitions:

- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product Supports Defense, Aerospace and Medical Applications

# **PACKAGE MATERIALS INFORMATION**

www.ti.com 12-Sep-2025

## TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LV8T541DGSR	VSSOP	DGS	20	5000	330.0	16.4	5.4	5.4	1.45	8.0	16.0	Q1
SN74LV8T541PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1
SN74LV8T541RKSR	VQFN	RKS	20	3000	180.0	12.4	2.8	4.8	1.2	4.0	12.0	Q1



www.ti.com 12-Sep-2025



### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LV8T541DGSR	VSSOP	DGS	20	5000	353.0	353.0	32.0
SN74LV8T541PWR	TSSOP	PW	20	2000	353.0	353.0	32.0
SN74LV8T541RKSR	VQFN	RKS	20	3000	210.0	185.0	35.0





### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.







### NOTES:

PowerPAD is a trademark of Texas Instruments.

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  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. No JEDEC registration as of September 2020.
- 5. Features may differ or may not be present.





### NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
- 8. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature numbers SLMA002 (www.ti.com/lit/slma002) and SLMA004 (www.ti.com/lit/slma004).
- 9. Size of metal pad may vary due to creepage requirement.
- 10. Vias are optional depending on application, refer to device data sheet. It is recommended that vias under paste be filled, plugged or tented.





NOTES: (continued)

- 11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 12. Board assembly site may have different recommendations for stencil design.



2.5 x 4.5, 0.5 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



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PLASTIC QUAD FLATPACK - NO LEAD



### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
  2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Vias are optional depending on application, refer to device data sheet. If some or all are implemented, recommended via locations are shown.



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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